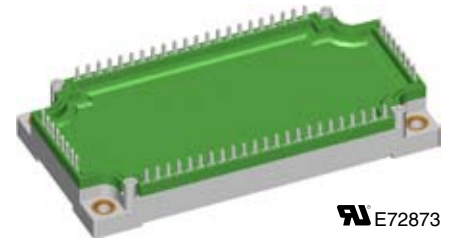
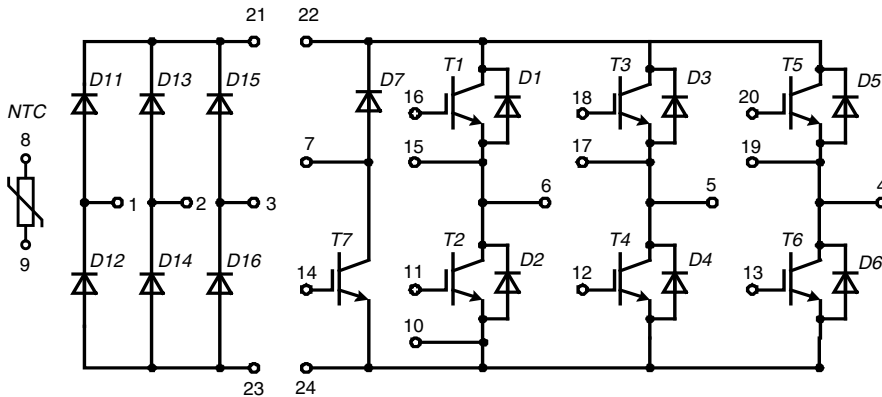


# Converter - Brake - Inverter Module (CBI3) with Trench IGBT technology



E72873

Three Phase Rectifier	Brake Chopper	Three Phase Inverter
$V_{RRM} = 2200 \text{ V}$	$V_{CES} = 1700 \text{ V}$	$V_{CES} = 1700 \text{ V}$
$I_{FAVM} = 60 \text{ A}$	$I_{C25} = 48 \text{ A}$	$I_{C25} = 74 \text{ A}$
$I_{FSM} = 550 \text{ A}$	$V_{CE(sat)} = 2.1 \text{ V}$	$V_{CE(sat)} = 2.0 \text{ V}$

Input Rectifier Bridge D11 - D16			
Symbol	Conditions	Maximum Ratings	
$V_{RRM}$		2200	V
$I_{FAV}$	$T_C = 80^\circ\text{C}$ ; sine $180^\circ$	40	A
$I_{DAVM}$	$T_C = 80^\circ\text{C}$ ; rectangular; $d = 1/3$ ; bridge	130	A
$I_{FSM}$	$T_C = 25^\circ\text{C}$ ; $t = 10 \text{ ms}$ ; sine 50 Hz	550	A
$P_{tot}$	$T_C = 25^\circ\text{C}$	110	W

Symbol	Conditions	Characteristic Values				
		min.	typ.	max.		
( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)						
$V_F$	$I_F = 50 \text{ A}$ ;	$T_{VJ} = 25^\circ\text{C}$		1.25	1.5	V
		$T_{VJ} = 125^\circ\text{C}$		1.25		V
$I_R$	$V_R = V_{RRM}$ ;	$T_{VJ} = 25^\circ\text{C}$		0.8	0.05	mA
		$T_{VJ} = 125^\circ\text{C}$				mA
$R_{thJC}$	(per diode)				1.1	K/W

### Application: AC motor drives with

- Input from single or three phase grid
- Three phase synchronous or asynchronous motor
- Electric braking operation

### Features

- High level of integration - only one power semiconductor module required for the whole drive
- IGBT technology with low saturation voltage, low switching losses and tail current, high RBSOA and short circuit ruggedness
- Epitaxial free wheeling diodes with Hiperfast and soft reverse recovery
- Industry standard package with insulated copper base plate and soldering pins for PCB mounting
- Temperature sense included

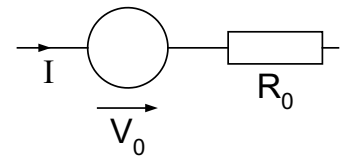
Output Inverter T1 - T6			
Symbol	Conditions	Maximum Ratings	
$V_{CES}$	$T_{VJ} = 25^{\circ}\text{C}$ to $150^{\circ}\text{C}$	1700	V
$V_{GES}$	Continuous	$\pm 20$	V
$I_{C25}$	$T_C = 25^{\circ}\text{C}$	74	A
$I_{C80}$	$T_C = 80^{\circ}\text{C}$	53	A
$I_{CM}$	$T_C = 80^{\circ}\text{C}$ ; $t_p = 1$ ms	100	A
$P_{tot}$	$T_C = 25^{\circ}\text{C}$	290	W

Symbol	Conditions	Characteristic Values				
		(T <sub>VJ</sub> = 25°C, unless otherwise specified)				
		min.	typ.	max.		
$V_{CE(sat)}$	$I_C = 50$ A; $V_{GE} = 15$ V	$T_{VJ} = 25^{\circ}\text{C}$		2.0	2.4	V
		$T_{VJ} = 125^{\circ}\text{C}$		2.4		V
$V_{GE(th)}$	$I_C = 2$ mA; $V_{GE} = V_{CE}$	5		6.5	V	
$I_{CES}$	$V_{CE} = V_{CES}$ ; $V_{GE} = 0$ V			0.4	mA	
			1.0		mA	
$I_{GES}$	$V_{CE} = 0$ V; $V_{GE} = \pm 20$ V			400	nA	
$C_{ies}$	$V_{CE} = 25$ V; $V_{GE} = 0$ V; $f = 1$ MHz		4.4		nF	
$Q_{Gon}$	$V_{CE} = 900$ V; $V_{GE} = 15$ V; $I_C = 75$ A		600		nC	
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $E_{on}$ $E_{off}$	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 900$ V; $I_C = 50$ A $V_{GE} = \pm 15$ V; $R_G = 8$ $\Omega$		250		ns	
			50		ns	
			500		ns	
			480		ns	
			11		mJ	
			12		mJ	
<b>RBSOA</b>	$I_C = I_{CM}$ ; $V_{GE} = 15$ V $R_G = 27$ $\Omega$ ; $T_{VJ} = 125^{\circ}\text{C}$	$V_{CEK} \leq V_{CES} - L_S di/dt$			V	
<b>t<sub>SC</sub> (SCSOA)</b>	$V_{CE} = 1000$ V; $V_{GE} = \pm 15$ V; $R_G = 27$ $\Omega$ $t_p \leq 10$ $\mu\text{s}$ ; non-repetitive; $T_{VJ} = 125^{\circ}\text{C}$		10		$\mu\text{s}$	
$R_{thJC}$			0.43		K/W	

Output Inverter D1 - D6			
Symbol	Conditions	Maximum Ratings	
$I_{F25}$	$T_C = 25^{\circ}\text{C}$	56	A
$I_{F80}$	$T_C = 80^{\circ}\text{C}$	39	A

Symbol	Conditions	Characteristic Values				
		min.	typ.	max.		
$V_F$	$I_F = 50$ A;	$T_{VJ} = 25^{\circ}\text{C}$		2.0	2.4	V
		$T_{VJ} = 125^{\circ}\text{C}$		2.0		V
$I_{RM}$	$I_F = 50$ A; $di_F/dt = -1200$ A/ $\mu\text{s}$ ; $T_{VJ} = 125^{\circ}\text{C}$ ; $V_R = 900$ V; $V_{GE} = 0$ V		80		A	
$Q_{rr}$		20		$\mu\text{C}$		
$t_{rr}$		650		ns		
$E_{rec}$		9		mJ		
$R_{thJC}$	(per diode)			0.65	K/W	

**Equivalent Circuits for Simulation**
**Conduction**

**IGBT (typ. at  $V_{GE} = 15$  V;  $T_J = 125^{\circ}\text{C}$ )**
*T1-T6*

$V_0 = 1.0$  V;  $R_0 = 25$  m $\Omega$

*T7*

$V_0 = 1.0$  V;  $R_0 = 28$  m $\Omega$

**Diode (typ. at  $T_J = 125^{\circ}\text{C}$ )**
*D1-D6*

$V_0 = 1.35$  V;  $R_0 = 15$  m $\Omega$

*D7*

$V_0 = 1.65$  V;  $R_0 = 37$  m $\Omega$

*D11-D16*

$V_0 = 0.83$  V;  $R_0 = 4.1$  m $\Omega$

**Brake Chopper T7**

Symbol	Conditions	Maximum Ratings	
$V_{CES}$	$T_{VJ} = 25^{\circ}\text{C}$ to $150^{\circ}\text{C}$	1700	V
$V_{GES}$	Continuous	$\pm 20$	V
$I_{C25}$	$T_C = 25^{\circ}\text{C}$	48	A
$I_{C80}$	$T_C = 80^{\circ}\text{C}$	34	A
$I_{CM}$	$T_C = 80^{\circ}\text{C}$ ; $t_p = 1$ ms	60	A
$P_{tot}$	$T_C = 25^{\circ}\text{C}$	200	W

Symbol	Conditions	Characteristic Values			
( $T_{VJ} = 25^{\circ}\text{C}$ , unless otherwise specified)					
		min.	typ.	max.	

$V_{CE(sat)}$	$I_C = 30$ A; $V_{GE} = 15$ V	$T_{VJ} = 25^{\circ}\text{C}$	1.9	2.2	V
		$T_{VJ} = 125^{\circ}\text{C}$	2.1		V
$V_{GE(th)}$	$I_C = 2$ mA; $V_{GE} = V_{CE}$		5	6.5	V
$I_{CES}$	$V_{CE} = V_{CES}$ ; $V_{GE} = 0$ V	$T_{VJ} = 25^{\circ}\text{C}$		0.3	mA
		$T_{VJ} = 125^{\circ}\text{C}$	0.6		mA
$I_{GES}$	$V_{CE} = 0$ V; $V_{GE} = \pm 20$ V			400	nA
$C_{iss}$	$V_{CE} = 25$ V; $V_{GE} = 0$ V; $f = 1$ MHz		4.4		nF
$Q_{Gon}$	$V_{CE} = 900$ V; $V_{GE} = 15$ V; $I_C = 30$ A		600		nC
$t_{d(on)}$	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 900$ V; $I_C = 30$ A $V_{GE} = \pm 15$ V; $R_G = 27$ $\Omega$		165		ns
$t_r$			40		ns
$t_{d(off)}$			700		ns
$t_f$			400		ns
$E_{off}$			7		mJ
$E_{on}$			6		mJ
<b>RBSOA</b>	$I_C = I_{CM}$ ; $V_{GE} = 15$ V $R_G = 27$ $\Omega$ ; $T_{VJ} = 125^{\circ}\text{C}$	$V_{CEK} \leq V_{CES} - L_S di/dt$			V
$t_{SC}$ <b>(SCSOA)</b>	$V_{CE} = 900$ V; $V_{GE} = \pm 15$ V; $R_G = 45$ $\Omega$ $t_p \leq 10$ $\mu\text{s}$ ; non-repetitive; $T_{VJ} = 125^{\circ}\text{C}$		10		$\mu\text{s}$
$R_{thJC}$				0.62	K/W

**Brake Chopper D7**

Symbol	Conditions	Maximum Ratings	
$V_{RRM}$	$T_{VJ} = 25^{\circ}\text{C}$ to $150^{\circ}\text{C}$	1700	V
$I_{F25}$	$T_C = 25^{\circ}\text{C}$	30	A
$I_{F80}$	$T_C = 80^{\circ}\text{C}$	21	A

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	

$V_F$	$I_F = 30$ A;	$T_{VJ} = 25^{\circ}\text{C}$	2.5	3.3	V
		$T_{VJ} = 125^{\circ}\text{C}$	2.6		V
$I_R$	$V_R = V_{RRM}$ ;	$T_{VJ} = 25^{\circ}\text{C}$		0.05	mA
		$T_{VJ} = 125^{\circ}\text{C}$	0.2		mA
$I_{RM}$	$I_F = 30$ A; $di_F/dt = -800$ A/ $\mu\text{s}$ ; $T_{VJ} = 125^{\circ}\text{C}$ $V_R = 900$ V		35		A
$t_{rr}$			700		ns
$R_{thJC}$	(per diode)			0.9	K/W



## Input Rectifier Bridge D11 - D16

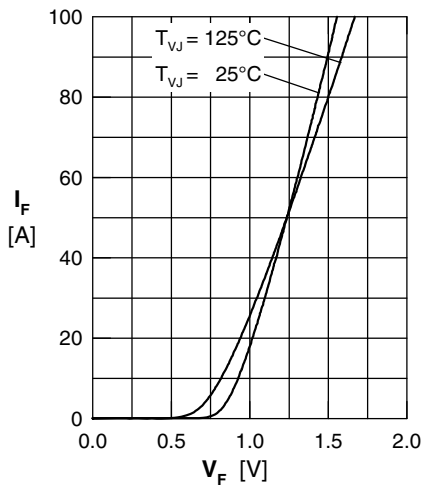


Fig. 1 Typ. forward current vs. voltage drop per diode

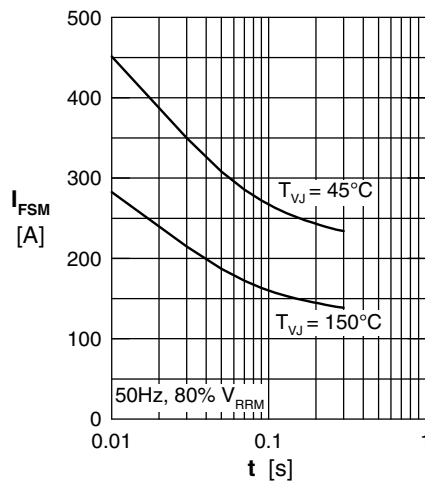


Fig. 2 Surge overload current

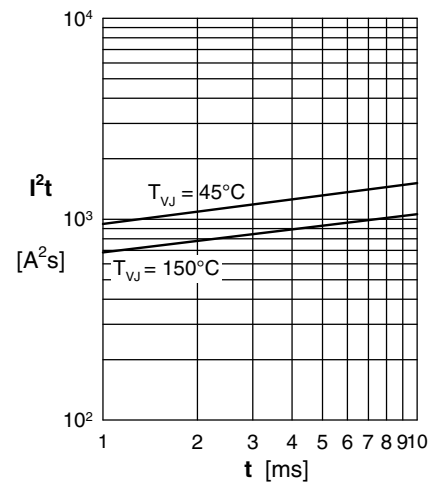


Fig. 3  $I^2t$  versus time per diode

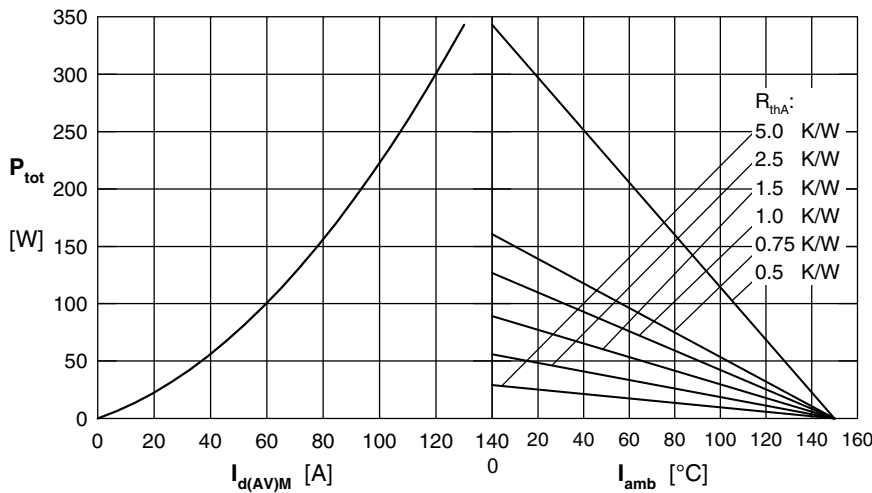


Fig. 4 Power dissipation versus direct output current & ambient temperature, sin 180°

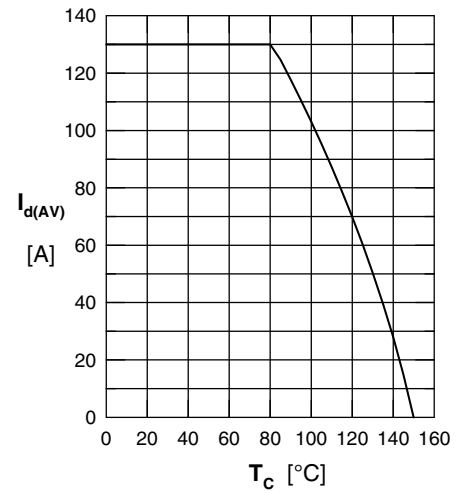


Fig. 5 Max. forward current vs. case temperature

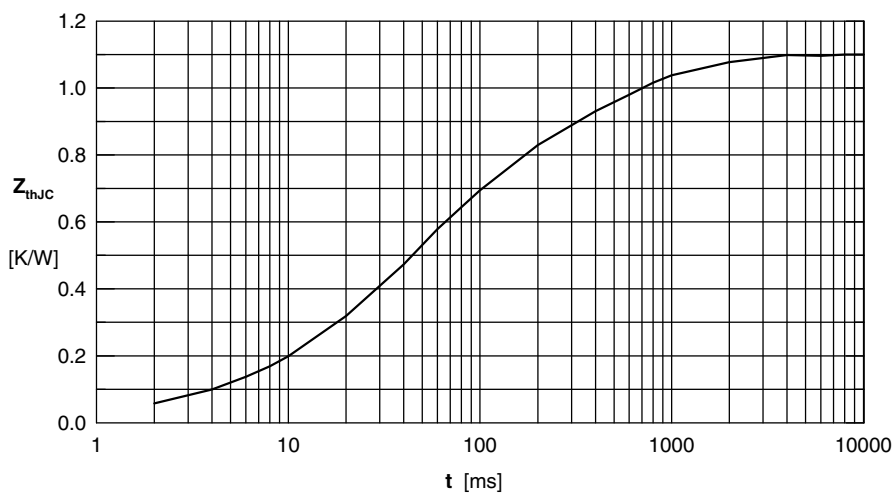
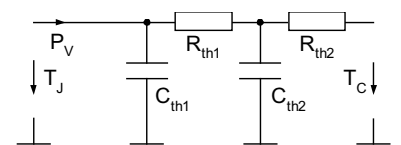


Fig. 6 Transient thermal impedance junction to case



	$R_i$	$\tau_i$
1	0.06	0.0085
2	0.024	0.001
3	0.586	0.045
4	0.114	0.85
5	0.317	0.35

**Output Inverter T1 - T6 / D1 - D6**

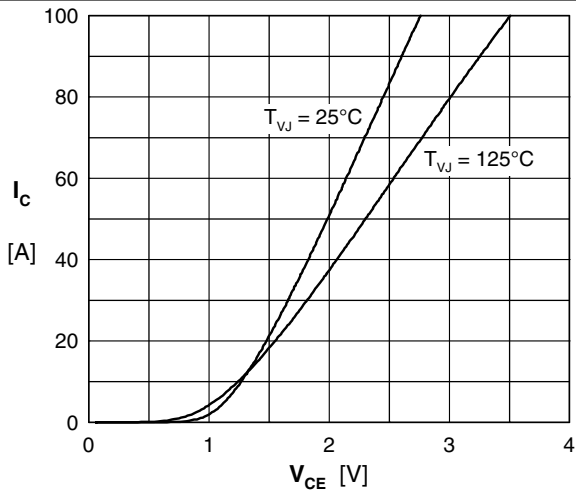


Fig. 7 Typical output characteristic

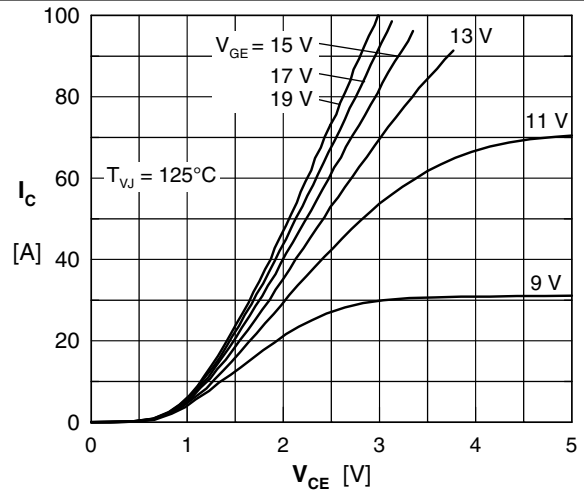


Fig. 8 Typical output characteristic

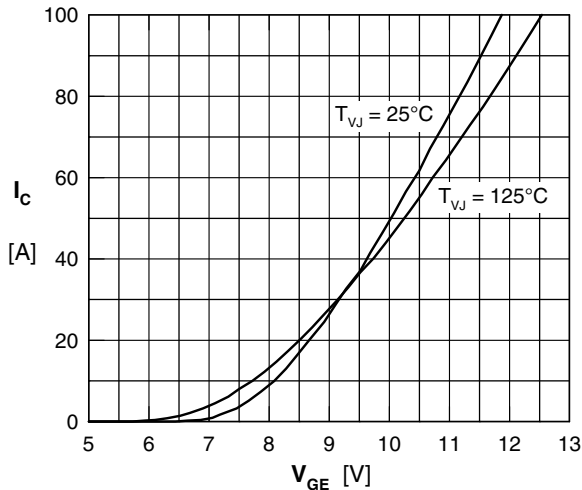


Fig. 9 Typical transfer characteristic

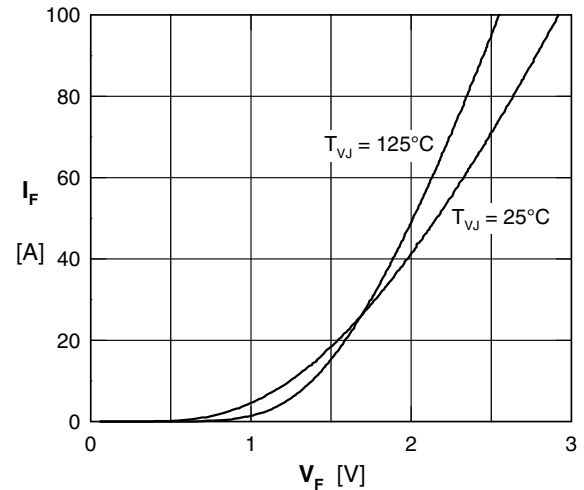


Fig. 10 Typical forward characteristic of free wheeling diode

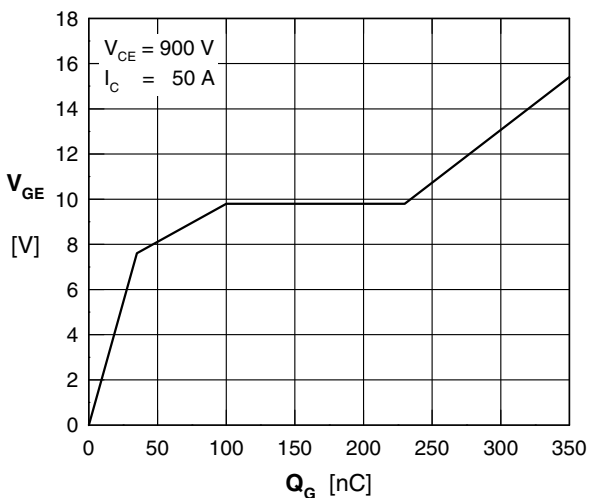


Fig. 11 Typical turn on gate charge

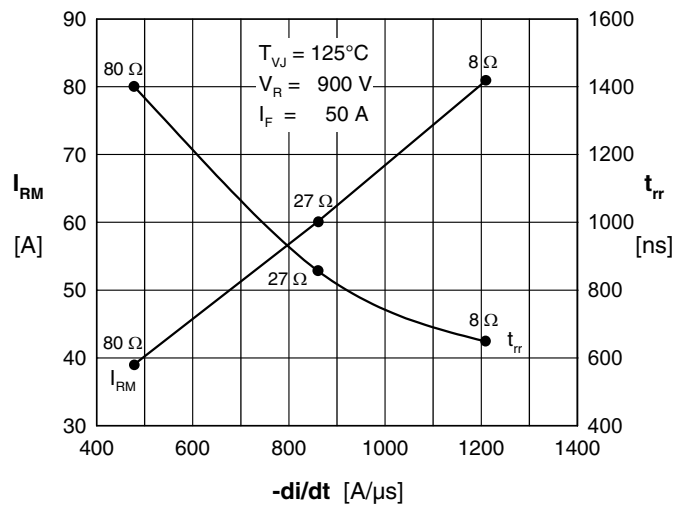


Fig. 12 Typ. turn-off characteristics of free wheeling diode

IXYS reserves the right to change limits, test conditions and dimensions.

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### Output Inverter T1 - T6 / D1 - D6

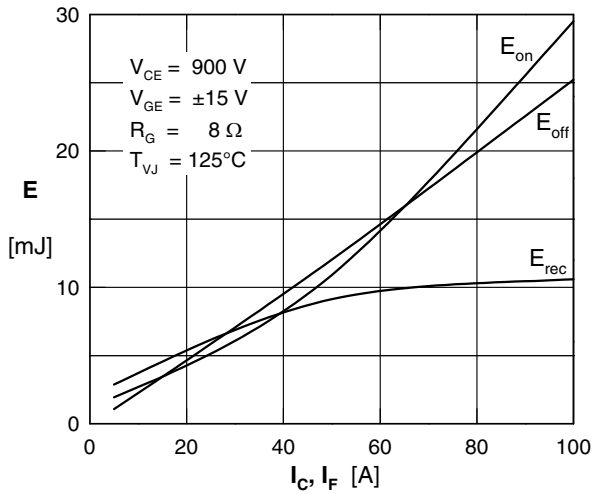


Fig. 13 Typ. turn on energy & switching times versus collector current

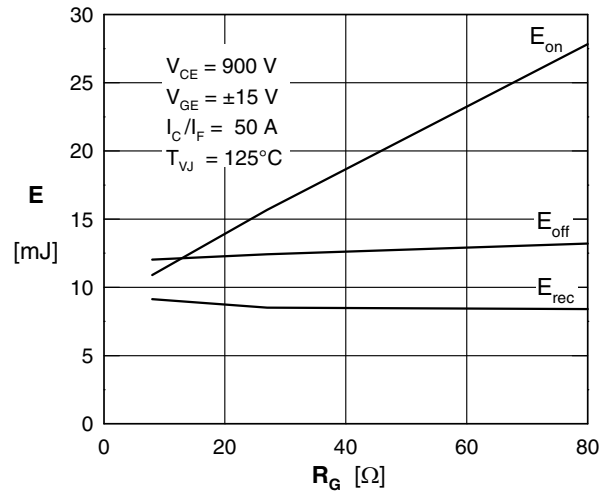


Fig. 14 Typ. turn off energy and switching times versus collector current

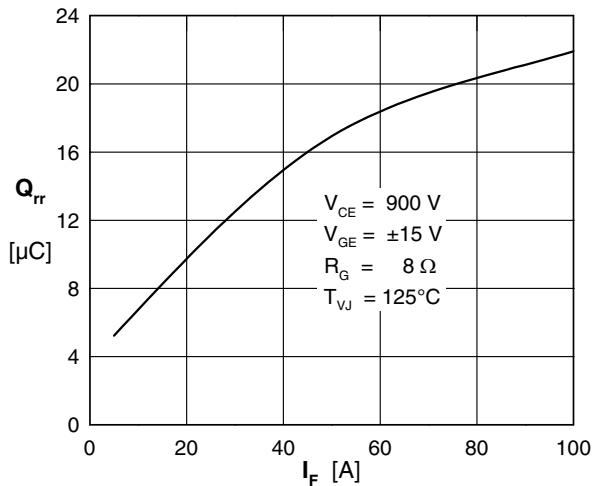


Fig. 15 Typical turn-off characteristics of free wheeling diode

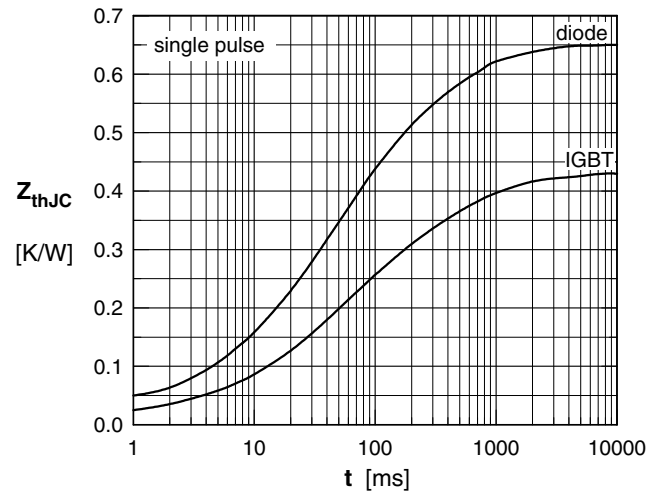


Fig. 16 Transient thermal impedance junction to case

### Temperature Sensor NTC

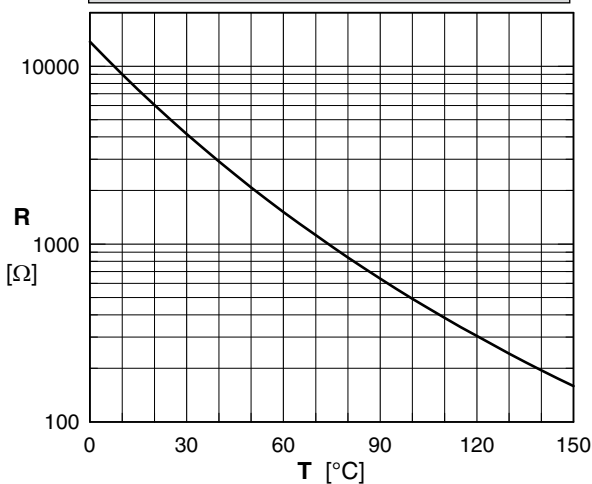
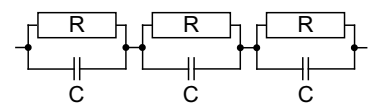


Fig. 17 Typ. NTC resistance vs. temperature

	IGBT		Diode	
	R <sub>i</sub>	τ <sub>i</sub>	R <sub>i</sub>	τ <sub>i</sub>
1	0.0326	0.0014	0.1941	0.0206
2	0.1311	0.0258	0.0542	0.0016
3	0.1492	0.1099	0.2549	0.0930
4	0.1169	0.6361	0.1461	0.5958



**Brake Chopper T7 / D7**

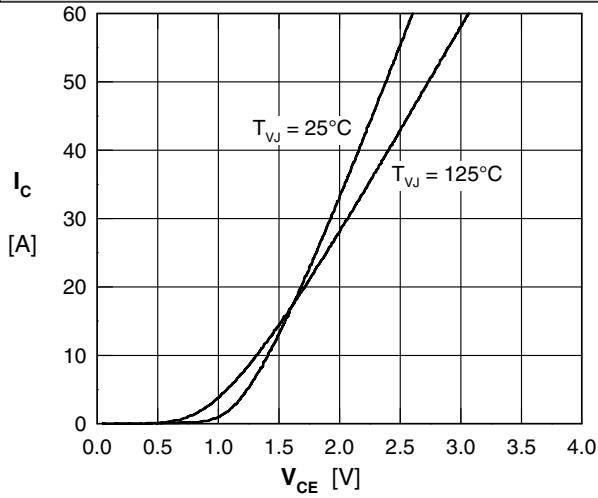


Fig. 18 Typical output characteristic

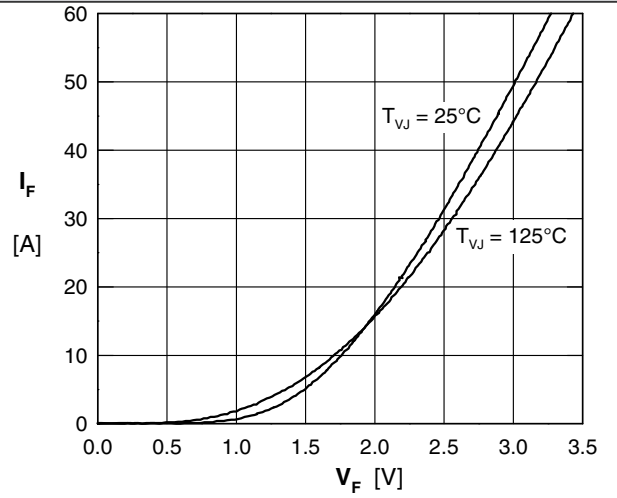


Fig. 19 Typ. forward characteristics of brake diode

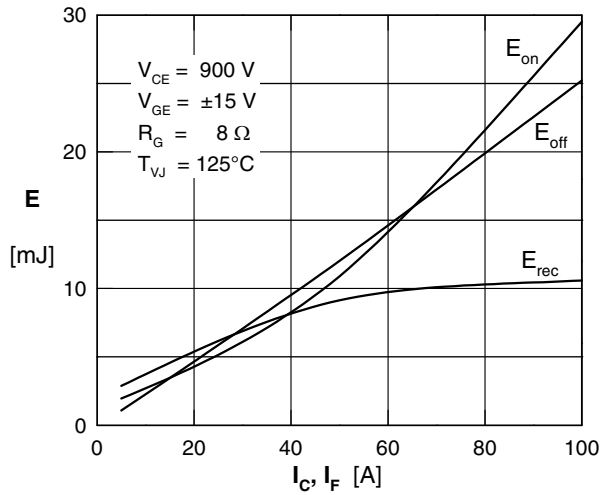


Fig. 20 Typ. turn on energy & switching times versus collector current

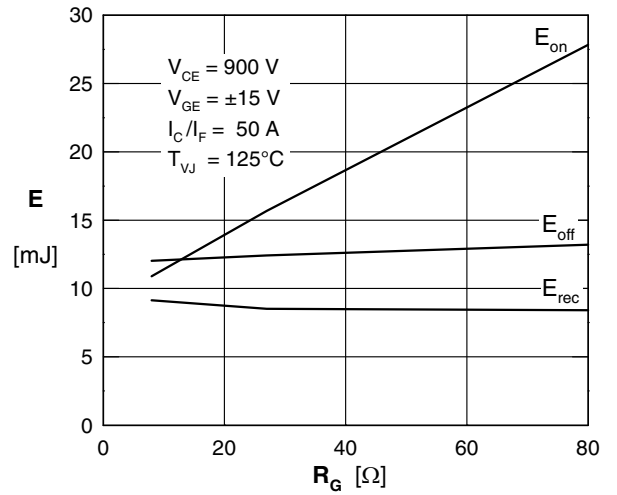


Fig. 21 Typ. turn off energy and switching times versus collector current

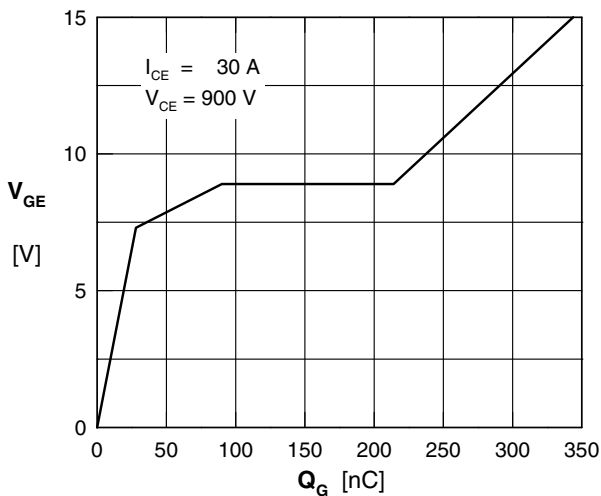


Fig. 22 Typ. turn on gate charge

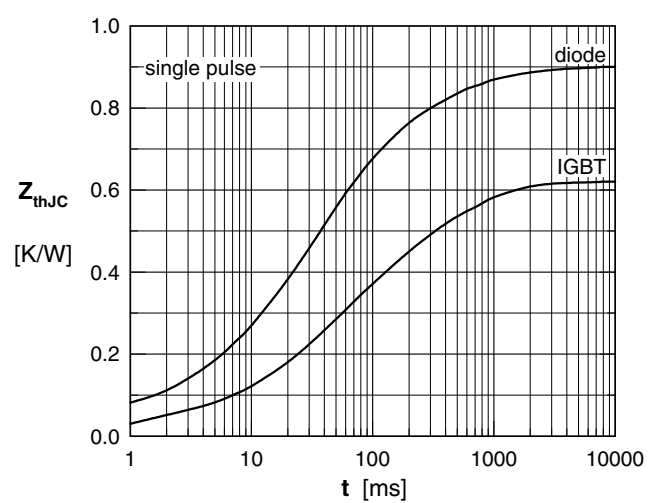


Fig. 23 Transient thermal impedance junction to case

IXYS reserves the right to change limits, test conditions and dimensions.

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